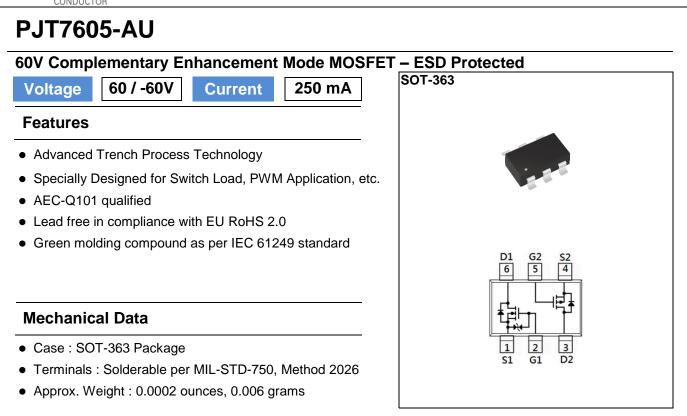
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	SEMI CONDUCTOR



#### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	N-Ch LIMIT	P-Ch LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	60	-60	V
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 20	<u>+</u> 20	V
Continuous Drain Current <sup>(Note 4)</sup>		ID	250	-250	mA
Pulsed Drain Current <sup>(Note 1)</sup>		Ідм	1000	-1000	mA
Power Dissipation	T <sub>a</sub> =25°C	_	350		mW
	Derate above 25°C	PD	2	mW/°C	
Operating Junction and Storage Terr	TJ,TSTG	-55~150		°C	
Typical Thermal Resistance - Junction to Ambient <sup>(Note 3)</sup>	Reja	357		°C/W	



#### N-Channel Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static	••••••					
Drain-Source Breakdown Voltage	BV <sub>DSS</sub> V <sub>GS</sub> =0V, I <sub>D</sub> = 250uA		60	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>GS(th)</sub> V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> = 250uA		1.5	2.5	V
	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> = 500mA	-	1.7	3	
Drain-Source On-State Resistance		$V_{GS}$ = 4.5V, $I_{D}$ = 200mA	-	2.2	4	Ω
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = 60V, V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	-	<u>+</u> 10	uA
Dynamic						
Total Gate Charge	Qg		-	0.7	-	
Gate-Source Charge	$Q_{gs}$	V <sub>DS</sub> =15V, I <sub>D</sub> =200mA, V <sub>GS</sub> =5V <sup>(Note 1,2)</sup>	-	0.3	-	nC
Gate-Drain Charge	$Q_gd$	VGS=3V (note the)	-	0.1	-	
Input Capacitance	Ciss		-	23	-	
Output Capacitance	Coss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1.0MHZ	-	13	-	pF
Reverse Transfer Capacitance	Crss		-	7	-	
Switching						
Turn-On Delay Time	td <sub>(on)</sub>		-	3	-	
Turn-On Rise Time	tr	$V_{DD}=30V, I_{D}=200mA,$	-	18	-	
Turn-Off Delay Time	td <sub>(off)</sub>	V <sub>GS</sub> =10V, R <sub>G</sub> =10Ω (Note 1,2)	-	9	-	ns
Turn-Off Fall Time	tf	(	-	22	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	ls		-	-	0.25	A
Diode Forward Voltage	V <sub>SD</sub>	Is= 200mA, V <sub>GS</sub> =0V	-	0.8	1.3	V



#### **P-Channel Electrical Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

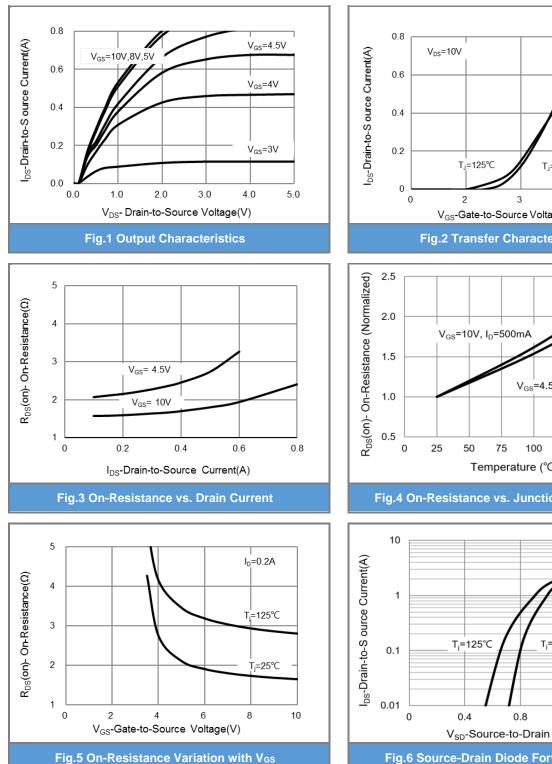
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	$V_{GS}=0V$ , $I_{D}=-250uA$	-60	-	-	V	
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> = -250uA	-0.8	-1.6	-2	V	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> = -10V, I <sub>D</sub> =-500mA	-	2.4	4	Ω	
		$V_{GS}$ = -4.5V, I <sub>D</sub> =-200mA	-	2.8	6		
		$V_{GS}$ = -2.5V, $I_{D}$ = -50mA	-	4.7	13		
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =-60V, V <sub>GS</sub> =0V	-	-	-1	uA	
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA	
Dynamic							
Total Gate Charge	Qg		-	1.1	-		
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =-25V, I <sub>D</sub> =-100mA, V <sub>GS</sub> =-4.5V <sup>(Note 1,2)</sup>	-	0.3	-	nC	
Gate-Drain Charge	$Q_gd$	VGS=-4.5V((1000 (),2)	-	0.2	-		
Input Capacitance	Ciss		-	51	-		
Output Capacitance	Coss	$V_{DS}$ =-25V, $V_{GS}$ =0V,	-	15	-	pF	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	2.2	-		
Switching							
Turn-On Delay Time	td <sub>(on)</sub>		-	4.8	-		
Turn-On Rise Time	tr	$V_{DD}$ =-25V, I <sub>D</sub> =-100mA,	-	19	-		
Turn-Off Delay Time	td <sub>(off)</sub>	V <sub>GS</sub> =-10V, R <sub>G</sub> =6Ω (Note 1,2)	-	52	-	ns	
Turn-Off Fall Time	tf		-	32	-		
Drain-Source Diode							
Maximum Continuous Drain-Source Diode Forward Current	ls		-	-	-250	mA	
Diode Forward Voltage	V <sub>SD</sub>	Is=-500mA, V <sub>GS</sub> =0V	-	-0.95	-1.3	V	

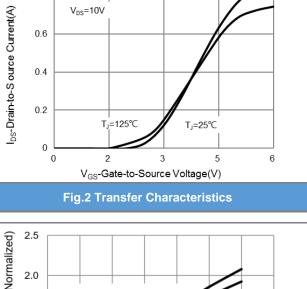
NOTES :

- 1. Pulse width
- 2. Essentially independent of operating temperature typical characteristics.
- 3. RoJA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.



#### N-Channel TYPICAL CHARACTERISTIC CURVES





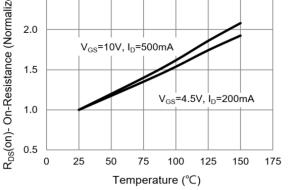
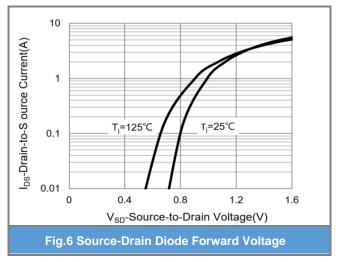


Fig.4 On-Resistance vs. Junction temperature





 $\begin{bmatrix} 10 & V_{DS} = 15V & & & & \\ I_{D} = 0.2A & & \\ I_{D} = 0.2A & & \\ I_{D} = 0.2A$ 

N-Channel TYPICAL CHARACTERISTIC CURVES

Fig.7 Gate-Charge Characteristics

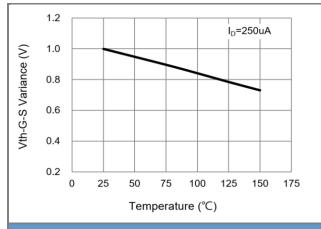
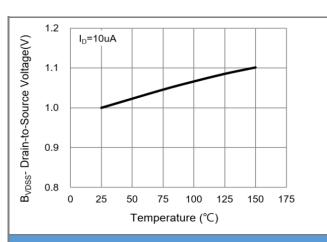


Fig.9 Threshold Voltage Variation with Temperature





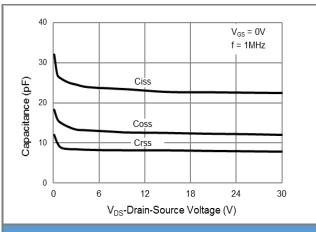
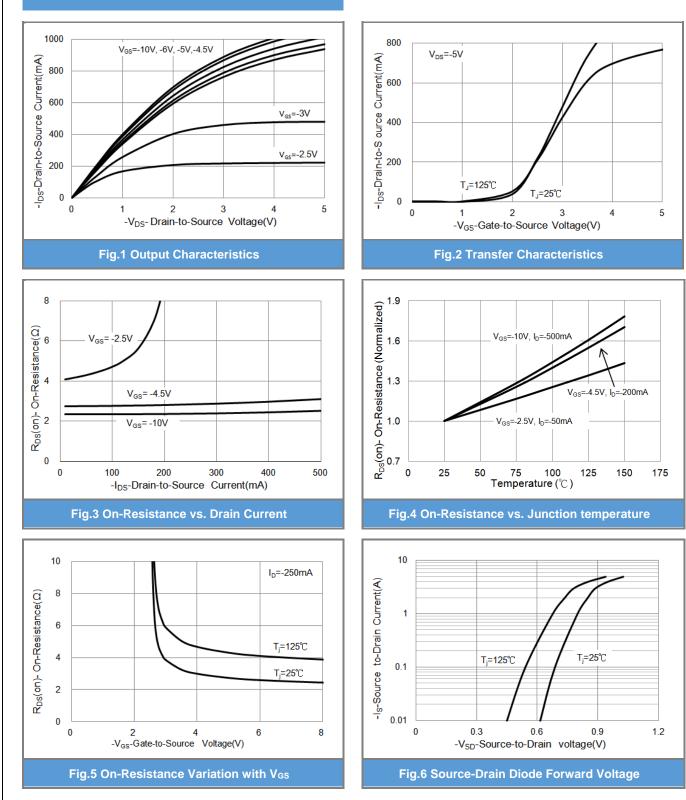


Fig.10 Capacitance vs. Drain-Source Voltage



P-Channel TYPICAL CHARACTERISTIC CURVES





#### P-Channel TYPICAL CHARACTERISTIC CURVES

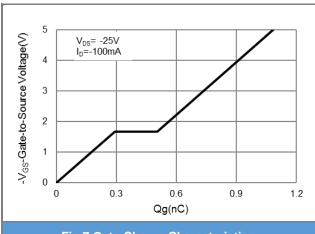
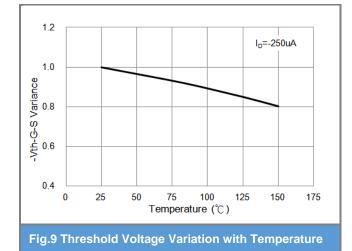
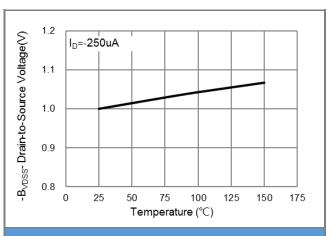


Fig.7 Gate-Charge Characteristics







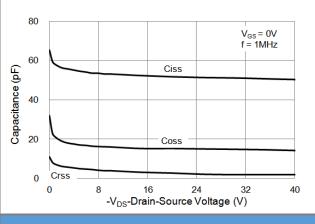


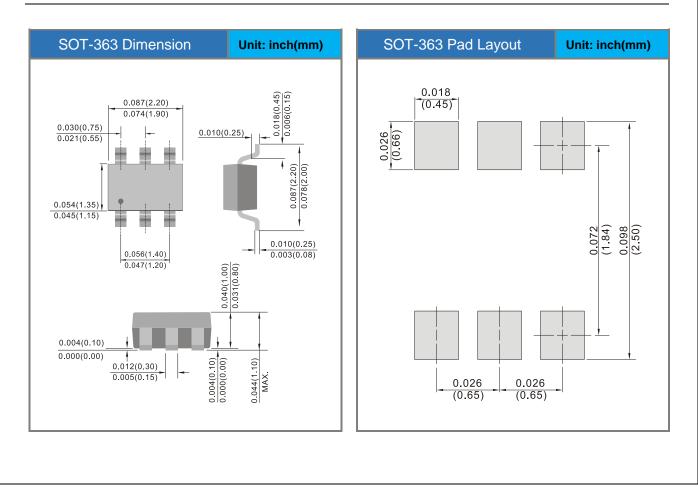
Fig.10 Capacitance vs. Drain-Source Voltage



#### **Product and Packing Information**

Part No.	Package Type	Packing Type	Marking
PJT7605-AU	SOT-363	3K pcs / 7" reel	T65

#### Packaging Information & Mounting Pad Layout





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